<table>
<thead>
<tr>
<th>Authors</th>
<th>Title</th>
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<tr>
<td><strong>Abou-Kandil, Ahmed</strong>; Afify, Nasser; Andreoni, Wanda; Curioni, Alessandro; Hong, Augustin J; Kim, Jeehwan; Khomyakov, Petr; Sadana, Devendra K;</td>
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<tr>
<td><strong>Abou-Kandil, Ahmed</strong>; Fogel, Keith E; Hong, Augustin J; Kim, Jeehwan; Saad, Mohamed; Sadana, Devendra K;</td>
<td>Temperature grading for band gap engineering of photovoltaic devices</td>
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<td><strong>Abou-Kandil, Ahmed</strong>; Hong, Augustin J; Kim, Jeehwan; Sadana, Devendra K;</td>
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<td>Tobail, Osama; <strong>Abou-Kandil, Ahmed</strong>; El-Ashry, Mostafa M; Kim, Jeehwan; Kozlowski, Paul M; Saad, Mohamed; Sadana, Devendra K;</td>
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<td>Tandem solar cell with improved tunnel junction</td>
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